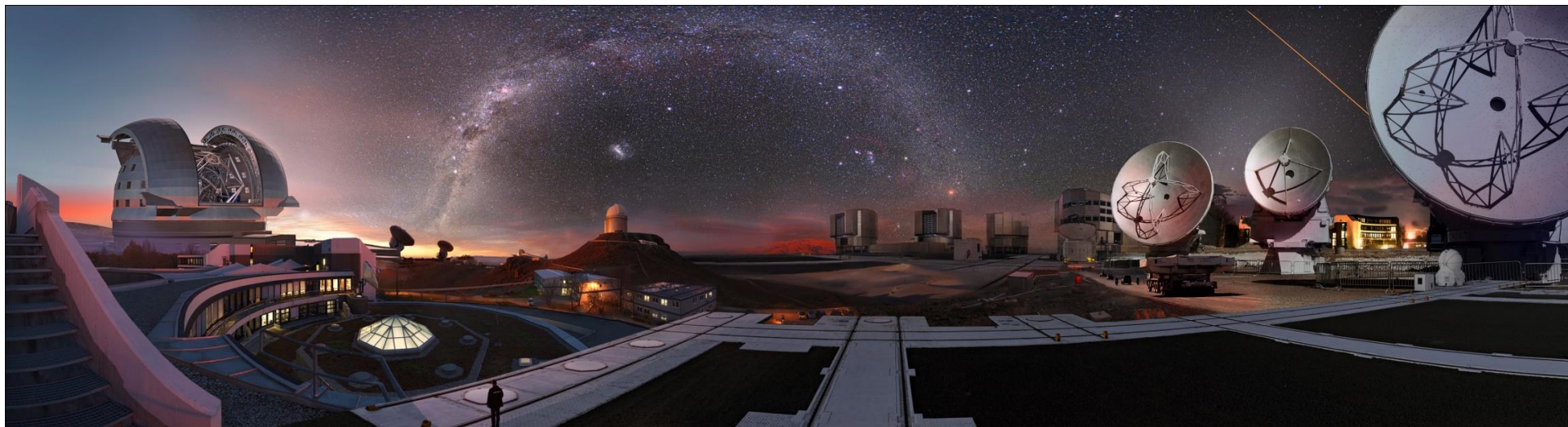




European Southern Observatory



Introduction to the organisation

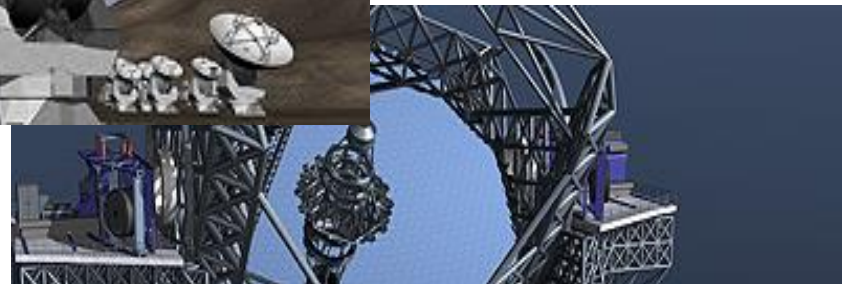
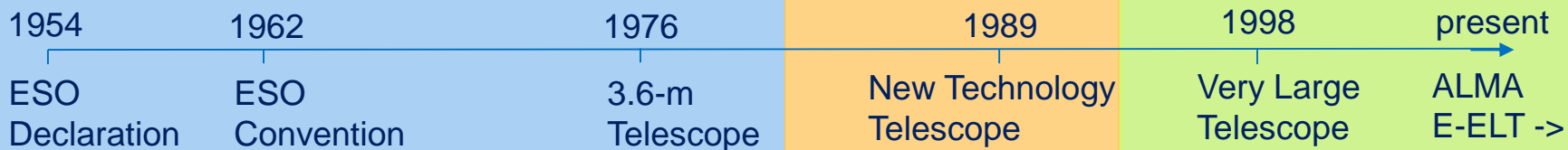


An evolving organisation

The beginning...

Building up expertise...

Among world leaders

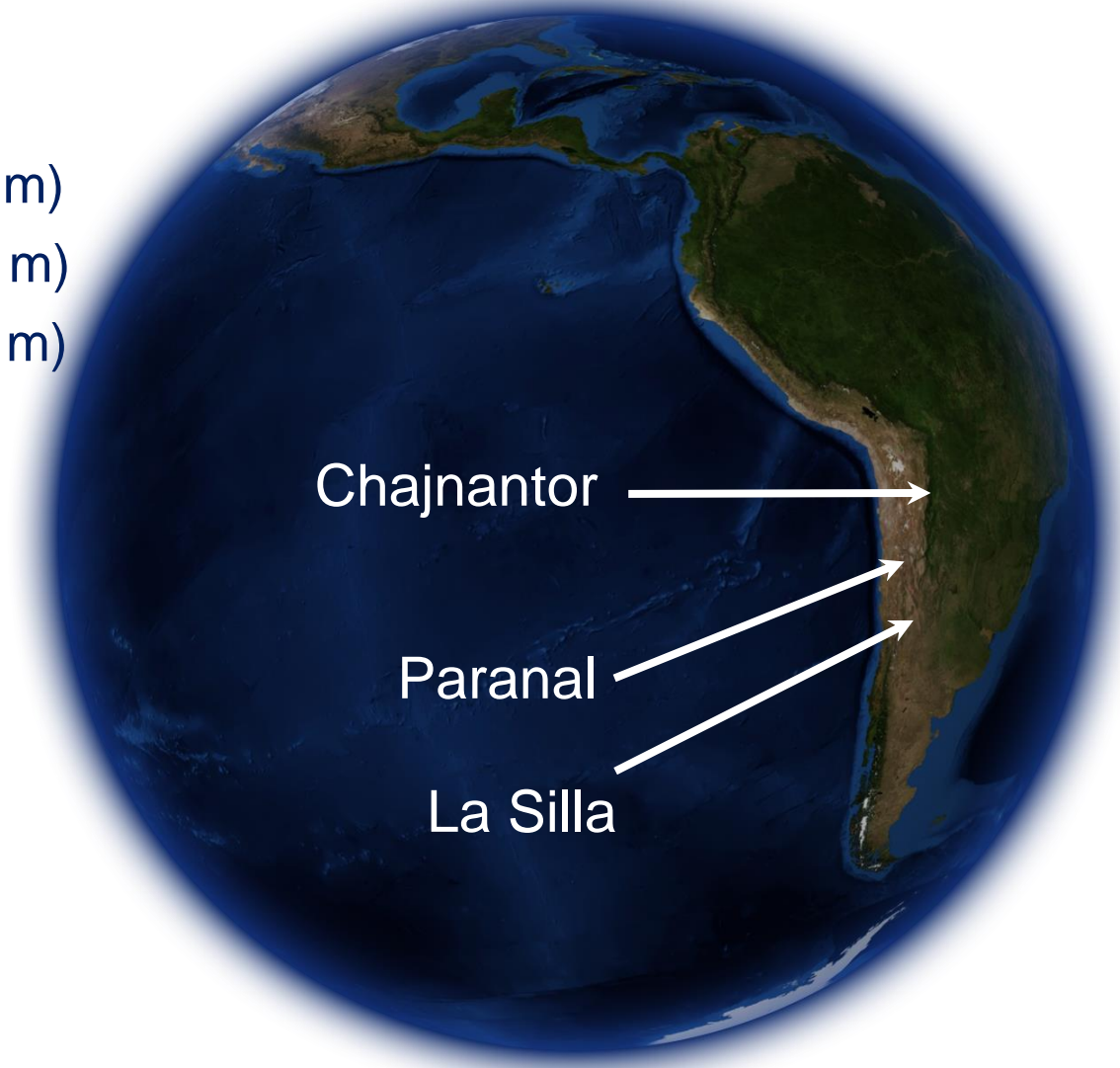


ESO today

- 16 member states
- Collaborations with Chile, US, East Asia, Canada
- ~ 680 staff at 5 main sites
 - Garching headquarters
 - Cerro Paranal Observatory(VLT)
 - Chajnantor (ALMA)
 - Vitacura (Santiago office)
 - La Silla Observatory (original site)

ESO's observatory sites in Chile

- Paranal (2600 m)
- La Silla (2400 m)
- Chajnantor (5000 m)



Paranal and the ESO Very Large Telescope





About 60 000 litres of water are consumed at Paranal each day, with two delivery trucks making the daily trip from Antofagasta.

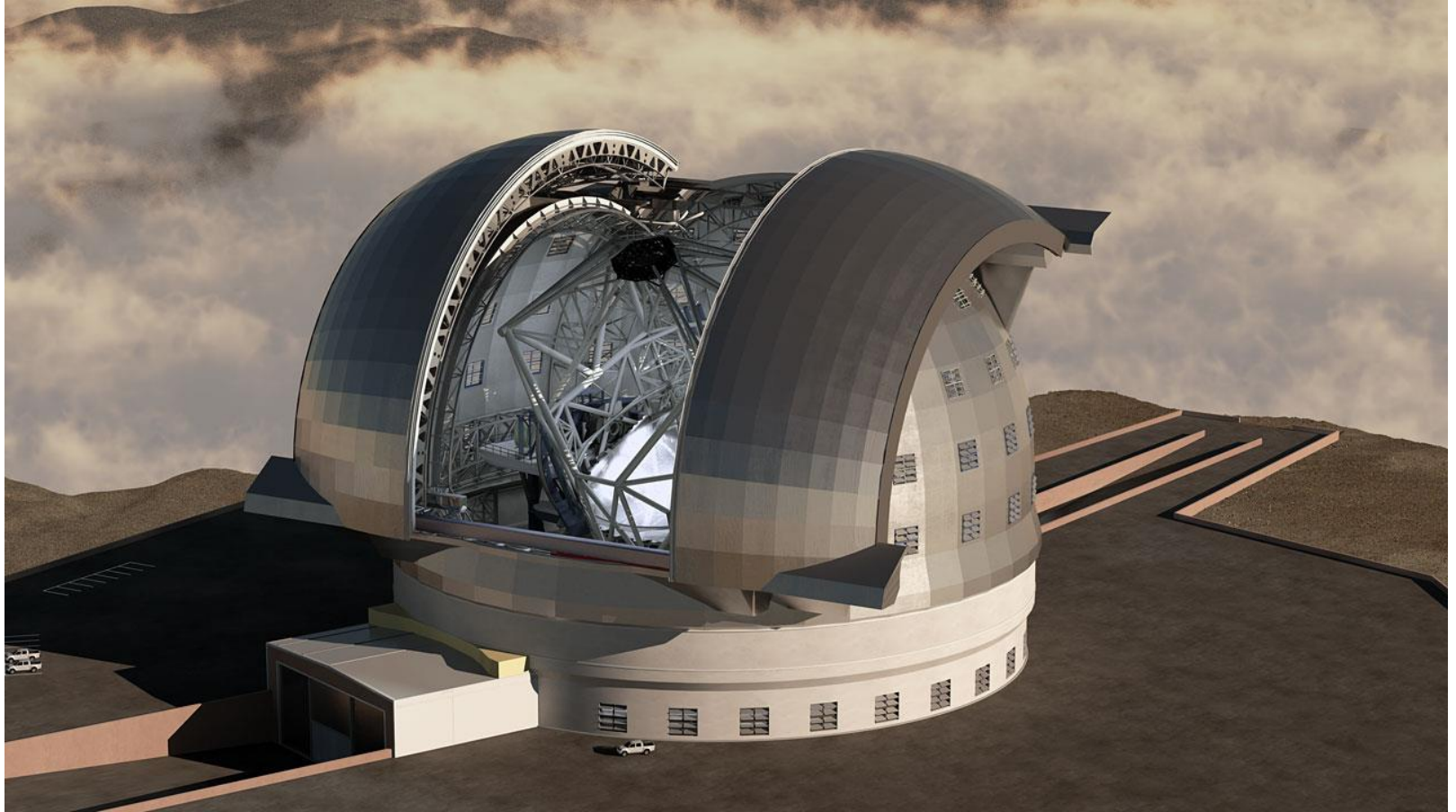


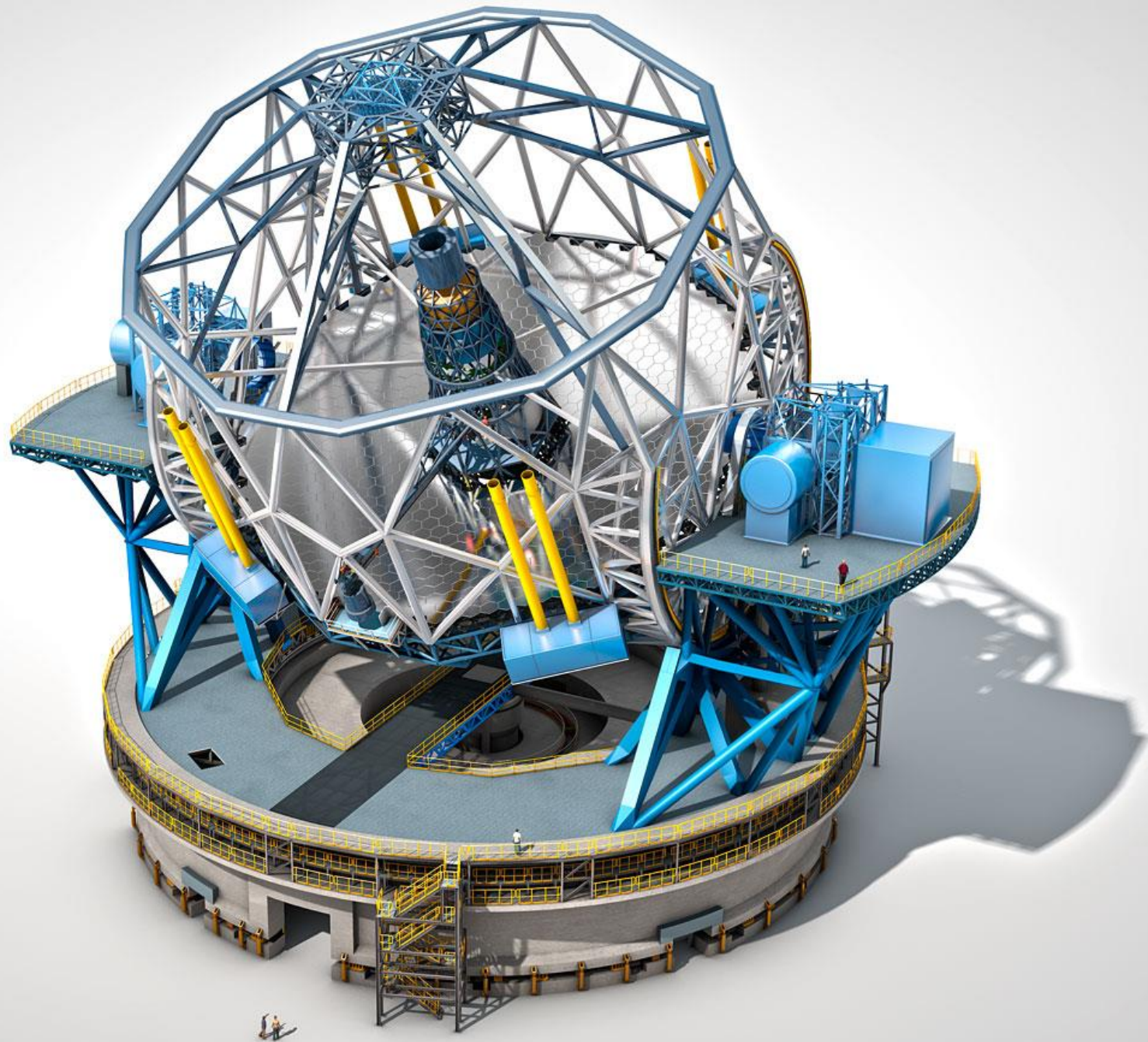
This is Cerro Chajnantor, at 5000-m altitude in the Atacama Desert.





European Extremely Large Telescope

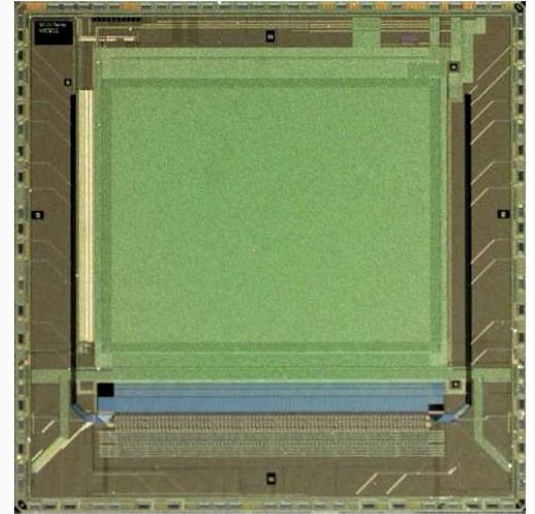




Cerro Armazones

Cerro Paranal

Scientific Imaging Using eAPD hybrid CMOS sensors



Simon Tulloch

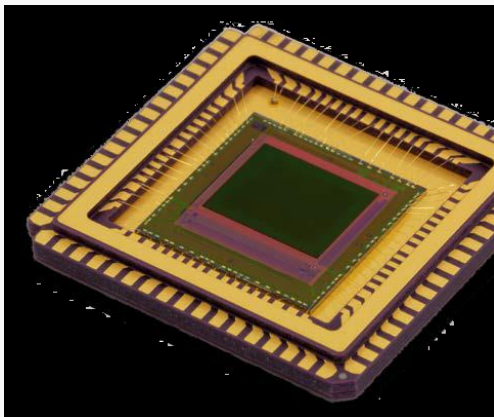
ESO

25/26 June 2018

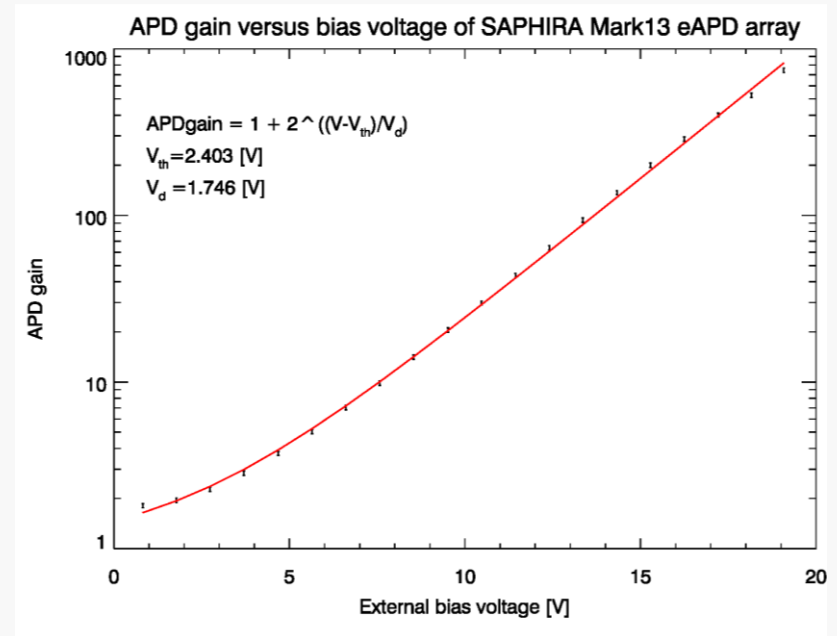
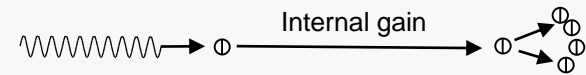
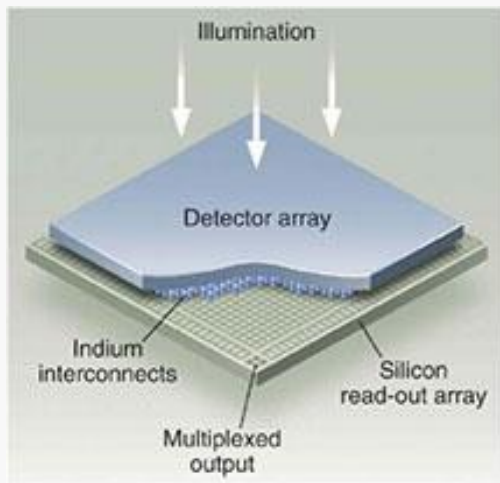
The Saphira from Leonardo

Currently being used for high-speed wavefront sensing at ESO. Potential science applications also.

Saphira, 320 x 256 x 24 μ m pixels



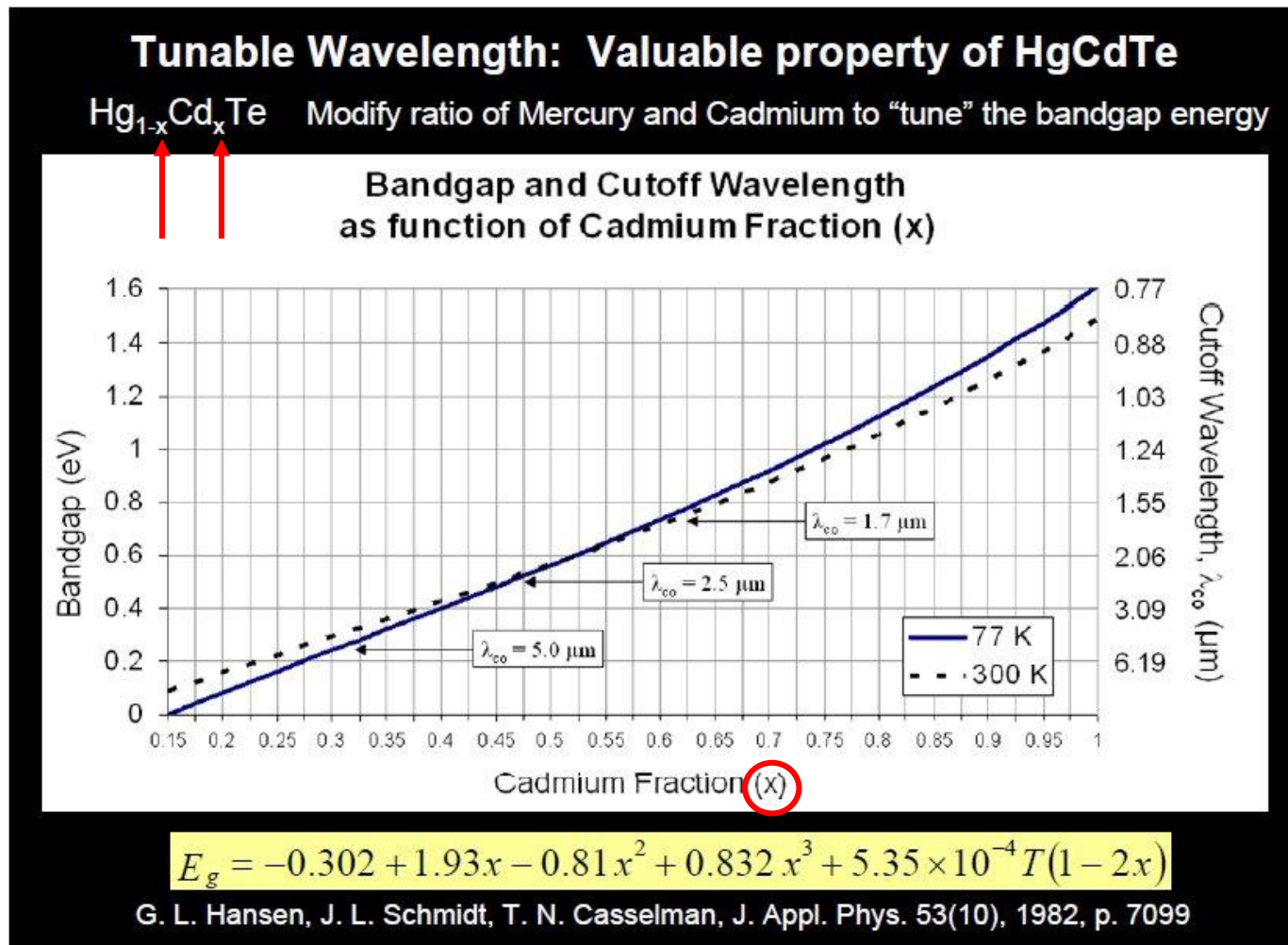
Larger versions are being developed (1k x 1k x 15 μ m).



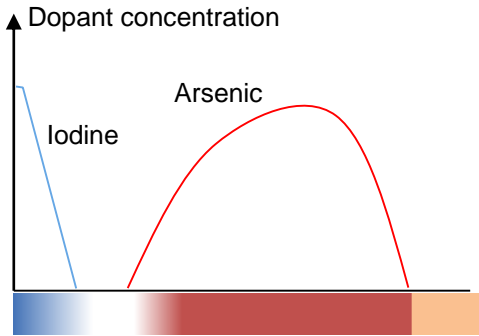
High gains possible with modest bias voltages

Mercury Cadmium Tellurium

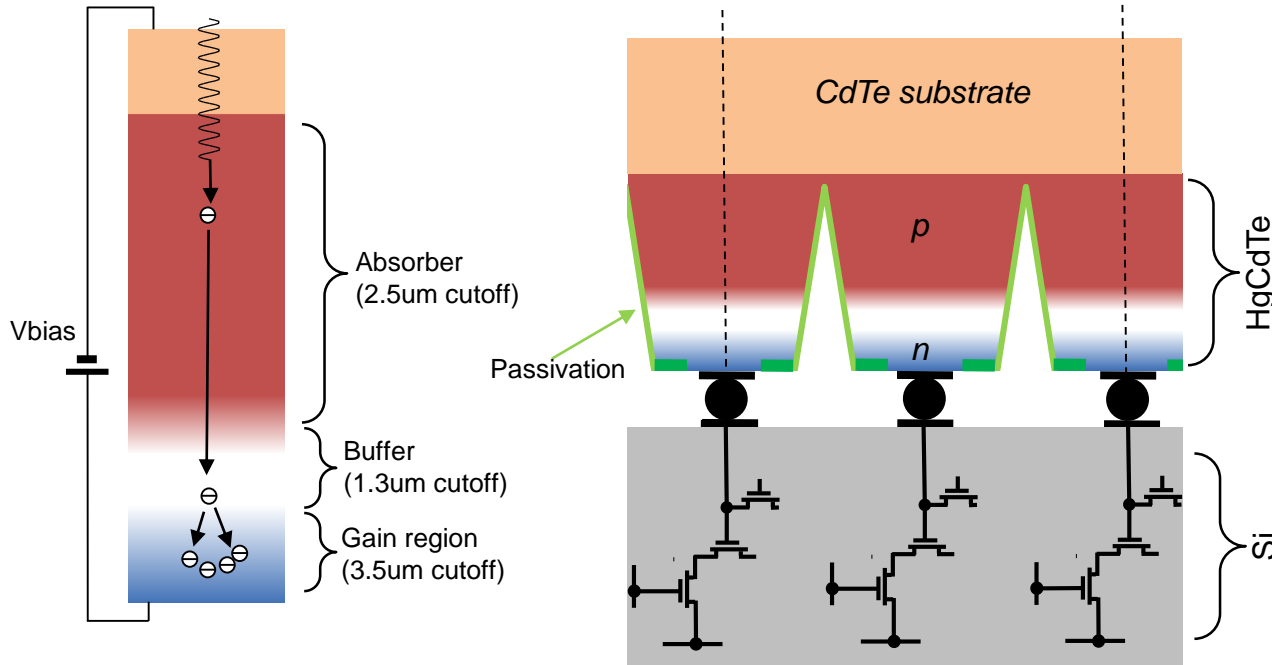
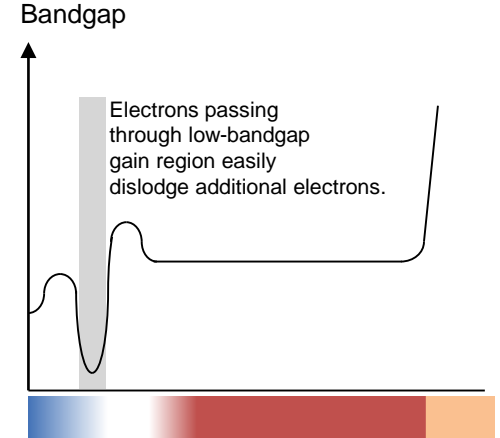
Also known as HgCdTe or “MCT”. From visible to Mid-IR sensitivity.



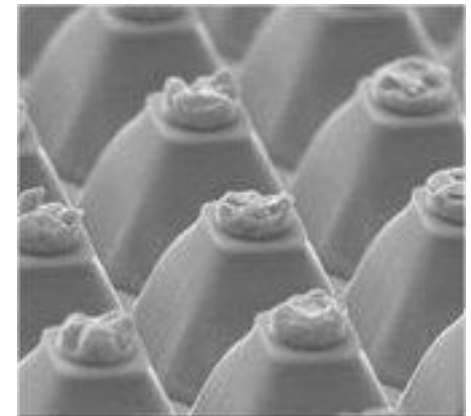
In-pixel charge amplification



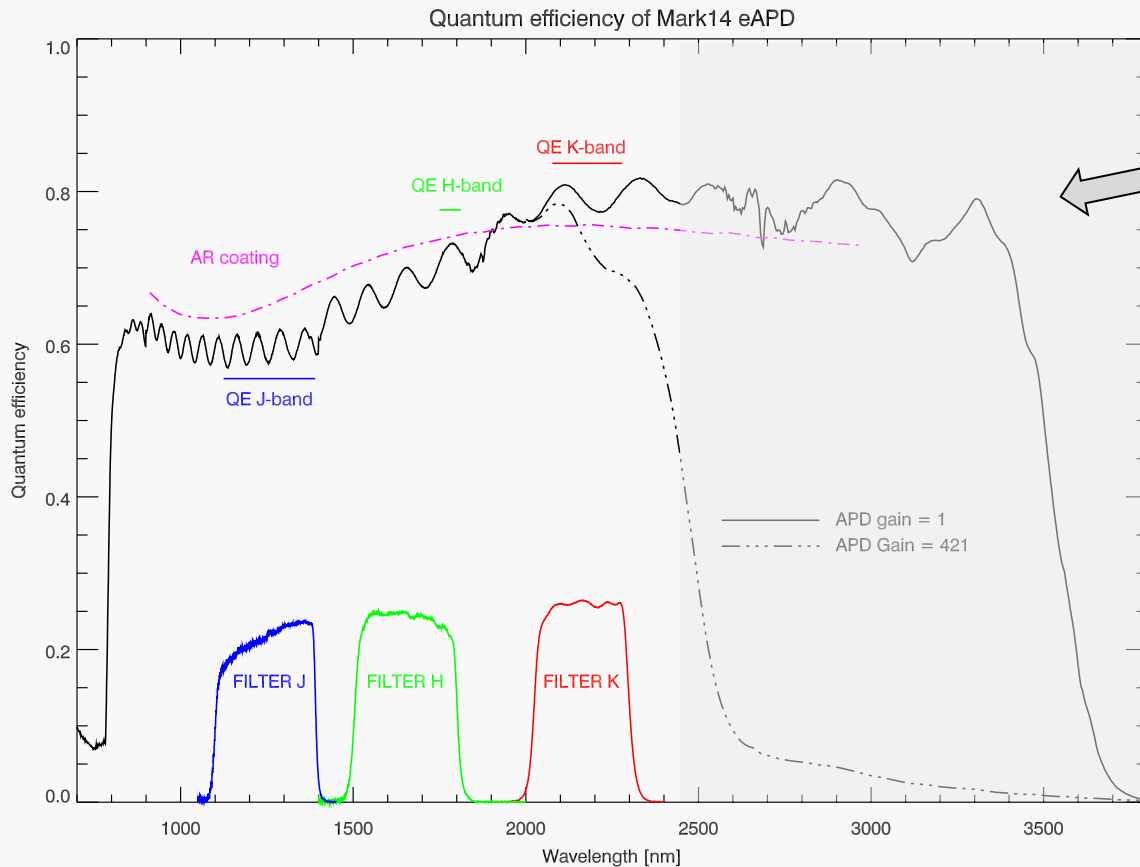
Requires "Bandgap engineering".
The cutoff wavelength of the HgCdTe material is modulated throughout the depth of the sensor.



Mesa structures prevent crosstalk between pixels



Quantum efficiency



© Gert Finger, ESO

At APD gain=1, photons are absorbed within the multiplication layer itself. response extends to 3.5 μ m.

When gain is applied the photoelectrons produced in this region will experience a variable gain depending on the depth at which they are created.

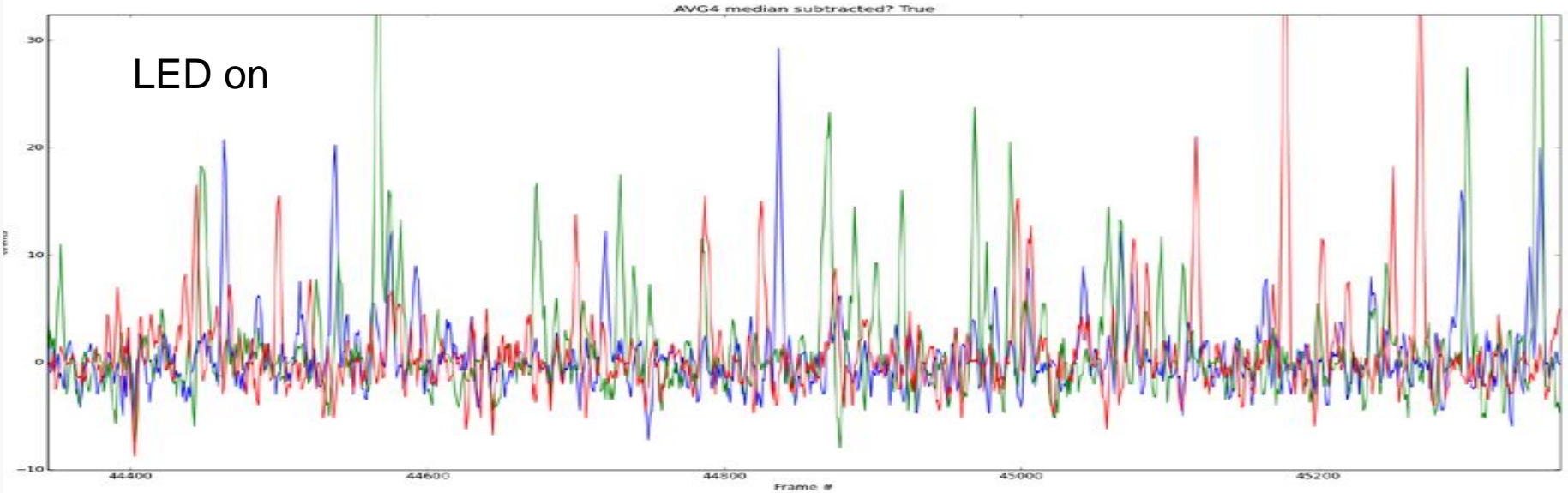
Important to block photons beyond 2.5 μ m with an external filter.



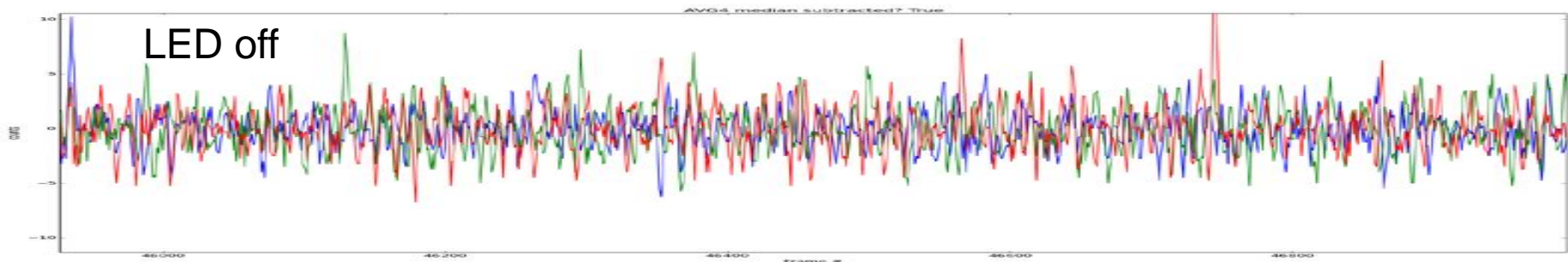
Photon counting demonstrated

Values of 3 pixels under weak illumination plotted as a function of frame number (read-reset-read mode)

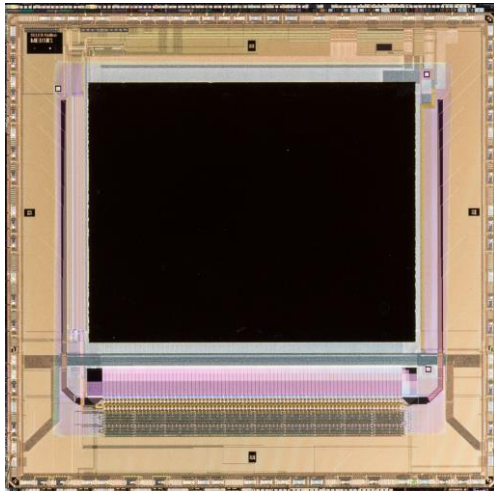
LED on



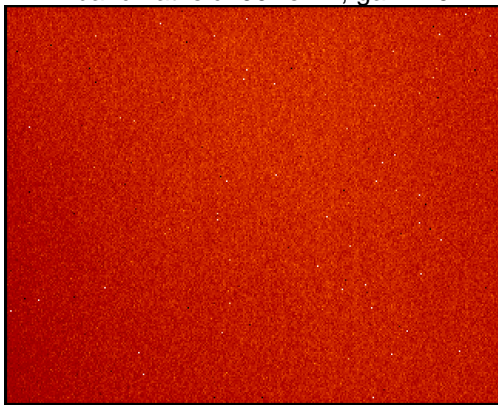
LED off



Saphira Characteristics



H-band flatfield. 90Kelvin, gain=102

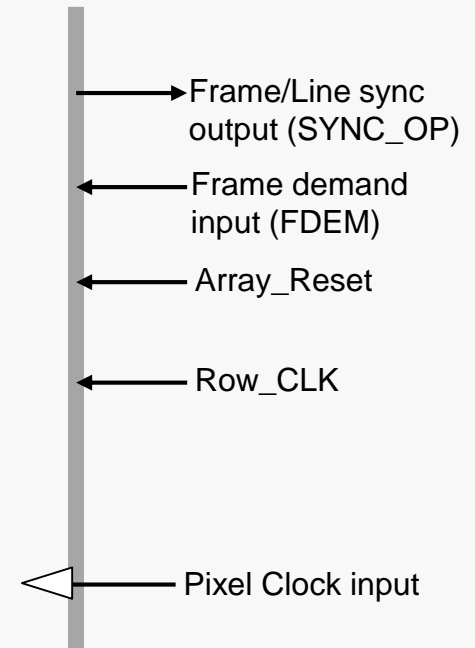
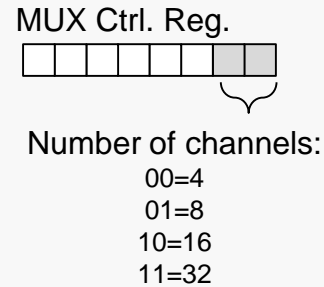
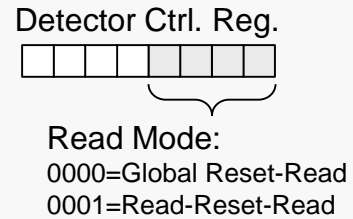
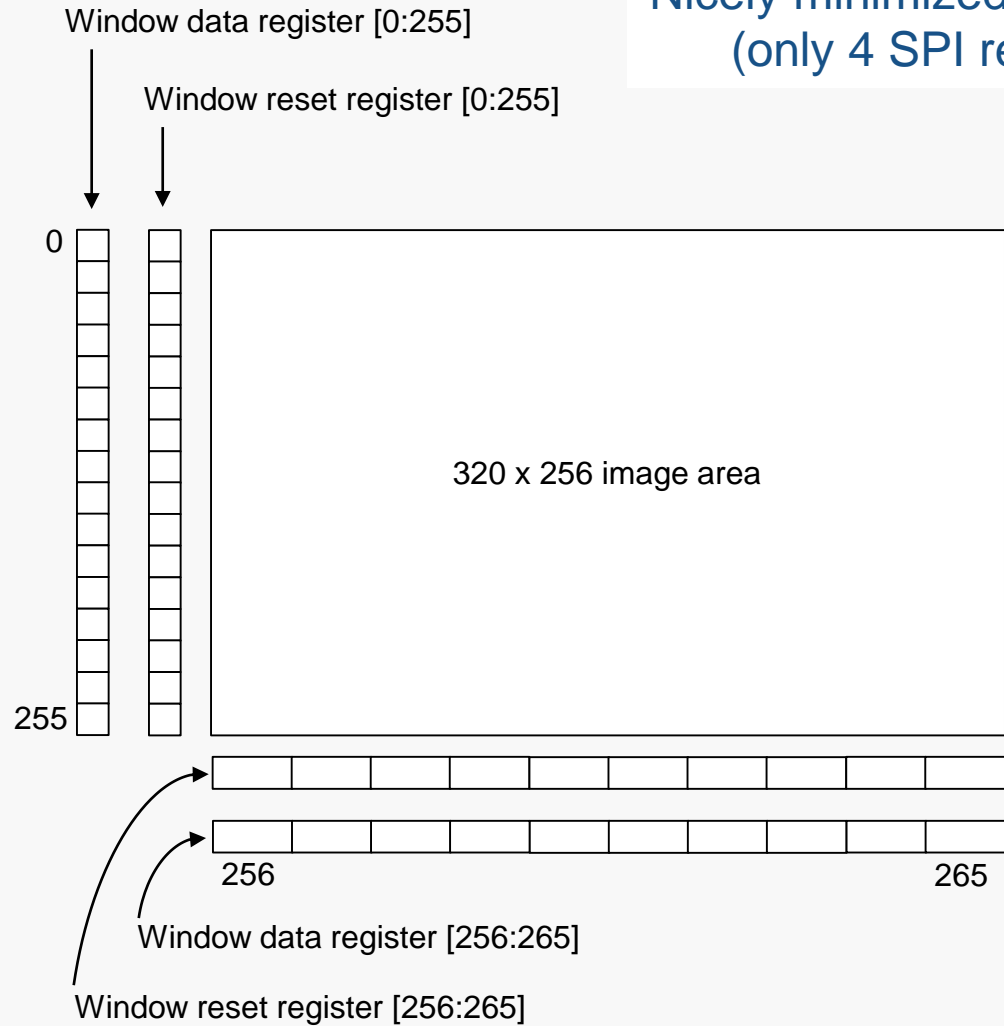


- Silicon : HgCdTe Hybrid sensor
- Metal Organic Vapor Phase Epitaxy
- Avalanche Photodiode Array
- 320 x 256 x 24um pixels
- Internal gain ~600 @20V bias
- BW 1-2.5um
- 10MHz analogue bandwidth
- 4,8,16 or 32 analogue outputs
- 2kHz frame rate for 128 x 128 window
- Effective read noise <math>< 1e^-</math>
- 3T pixels
- 150mW power at full speed and gain
- Node sensitivity 6.6uV/e
- 175ke full well
- Low glow
- $10^{-3} e \text{ pix}^{-1} \text{ s}^{-1}$ dark current (at low gain)
- Excellent cosmetics even at high gain
- Efficient, highly simplified operation.
- Global and line reset modes.

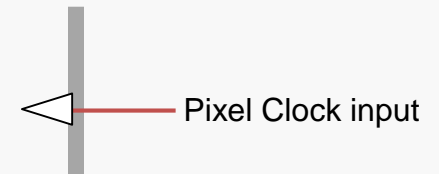
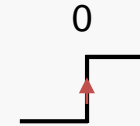
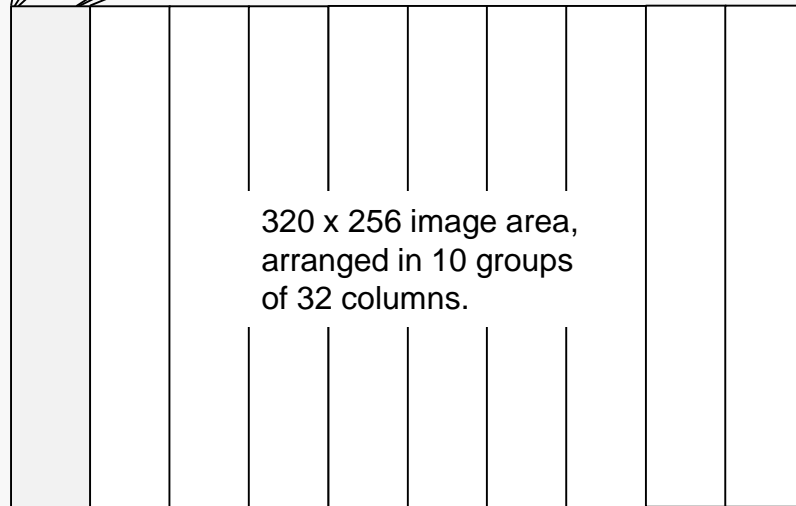
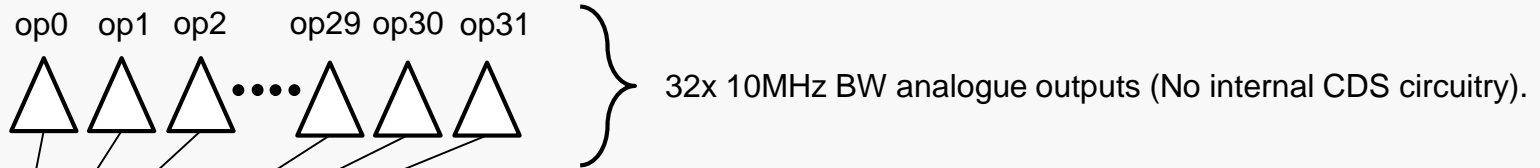


Key Registers/Pins

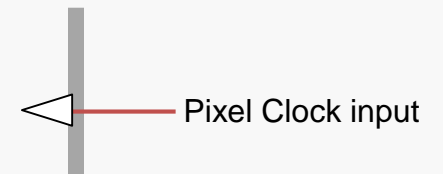
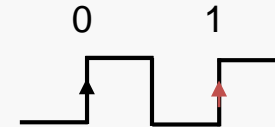
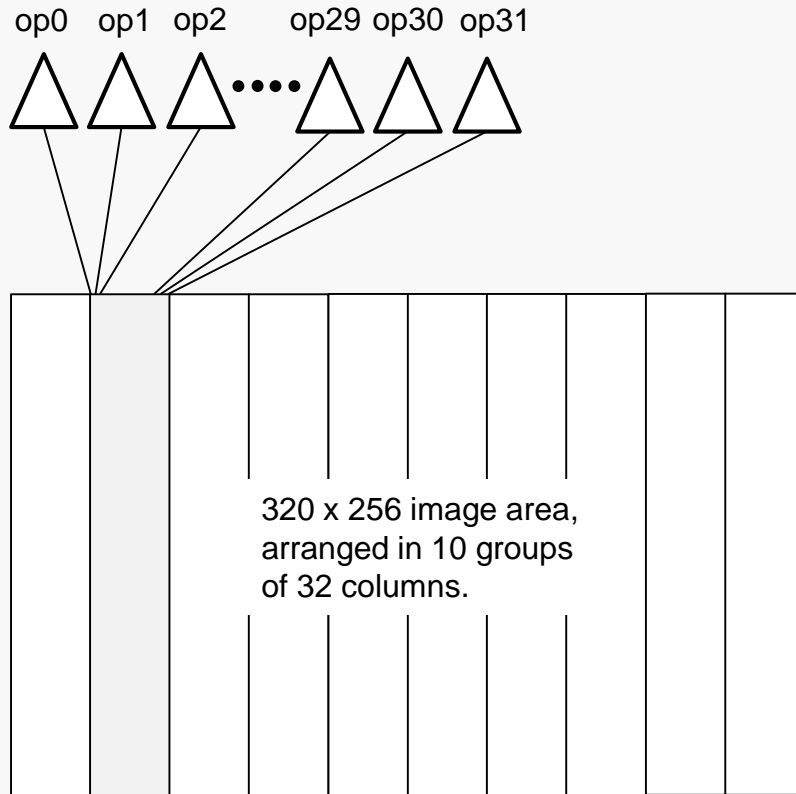
Nicely minimized register set
(only 4 SPI registers)



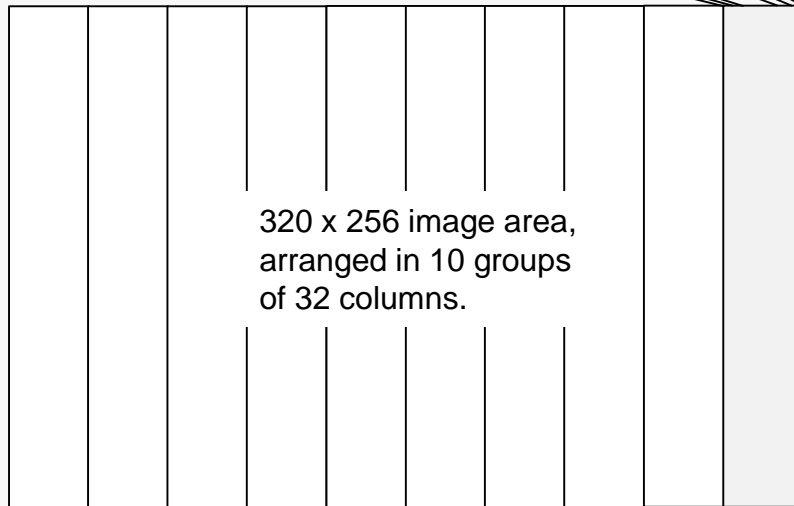
Output Multiplexing



Output Multiplexing

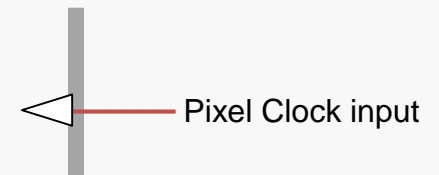
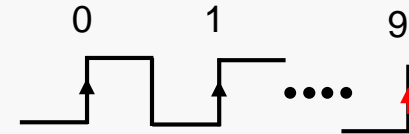


Output Multiplexing



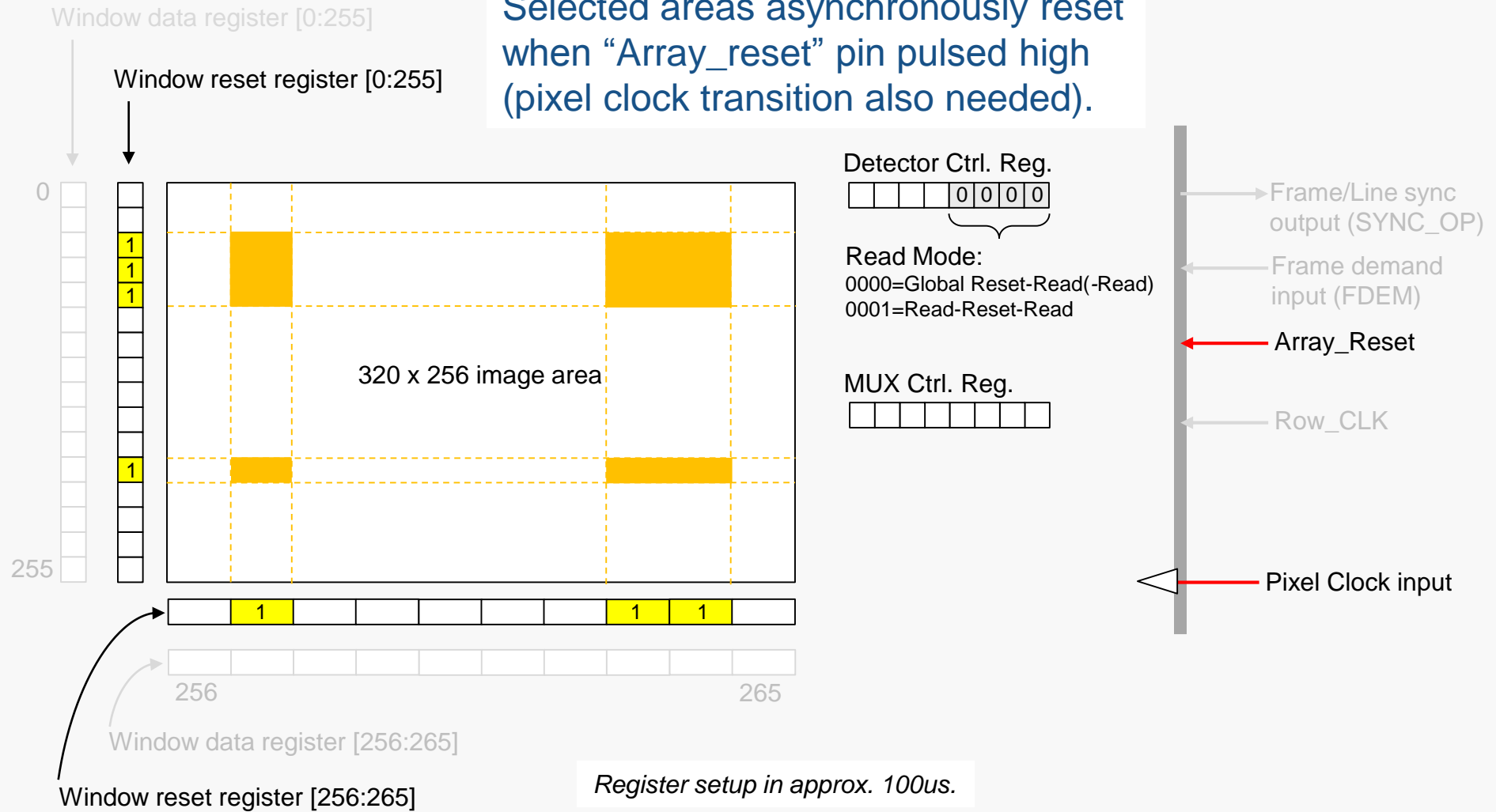
Full multiplex advantage for objects falling entirely within one column group: up to 20kHz frame rate.

10 clock transitions reads a complete line



Window reset register

Selected areas asynchronously reset when "Array_reset" pin pulsed high (pixel clock transition also needed).



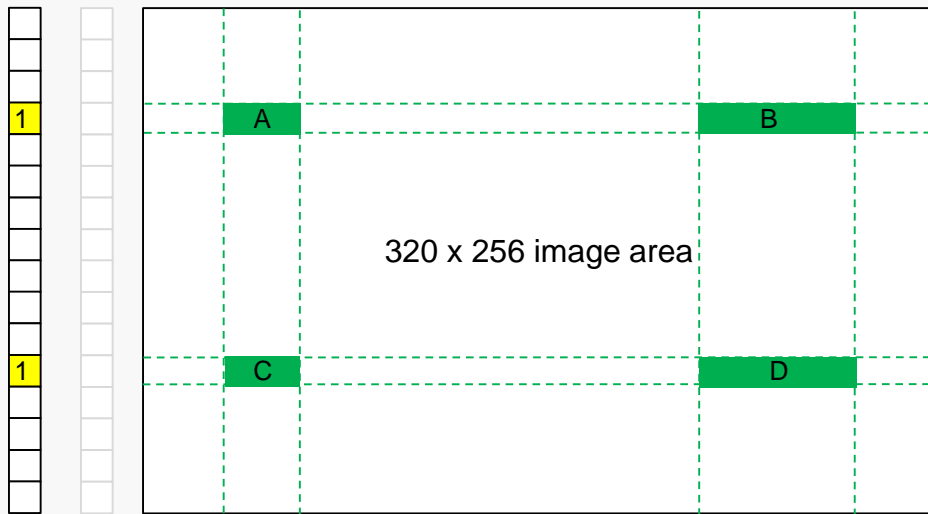


Global Reset-Read(-Read-Read...)

Following the global reset the selected areas are then read by first pulsing FDEM.....

Window data register [0:255]

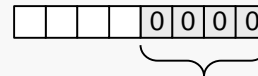
Window reset register [0:255]



Window data register [256:265]

Window reset register [256:265]

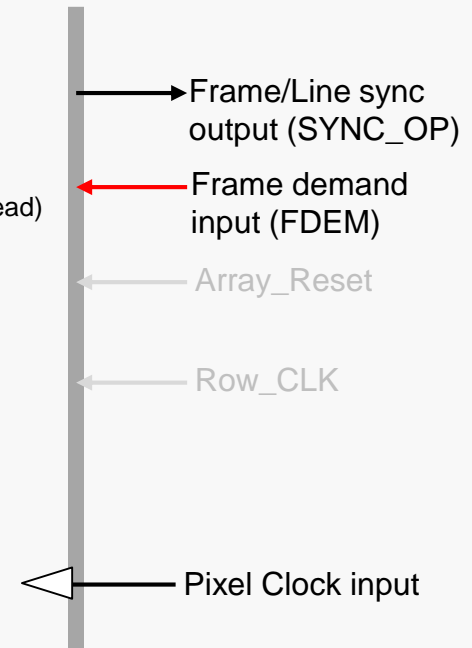
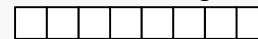
Detector Ctrl. Reg.



Read Mode:

0000=Global Reset-Read(-Read)
0001=Read-Reset-Read

MUX Ctrl. Reg.





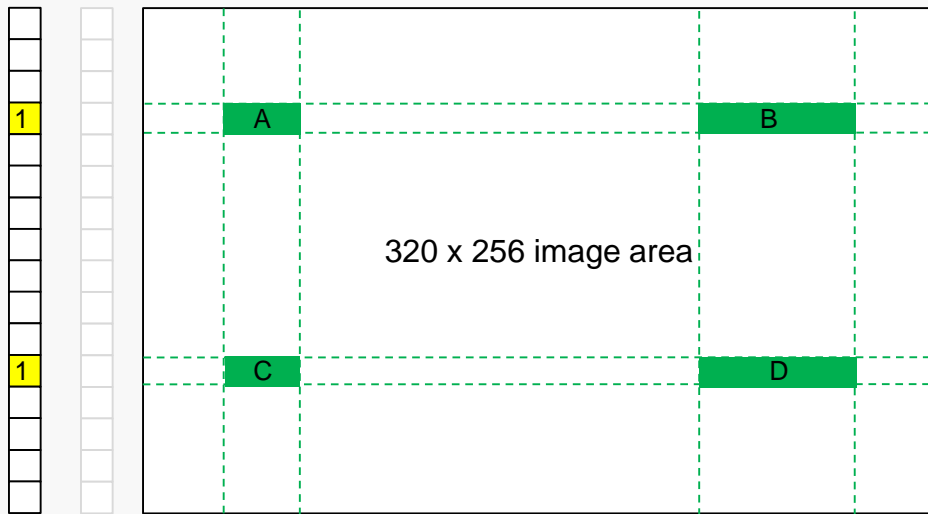
Global Reset-Read(-Read-Read...)

...and then by applying the following number of pixel clocks:

$$((\text{number of columns groups} + 1) * \text{number of rows}) + 1 = 9$$

Window data register [0:255]

Window reset register [0:255]



320 x 256 image area

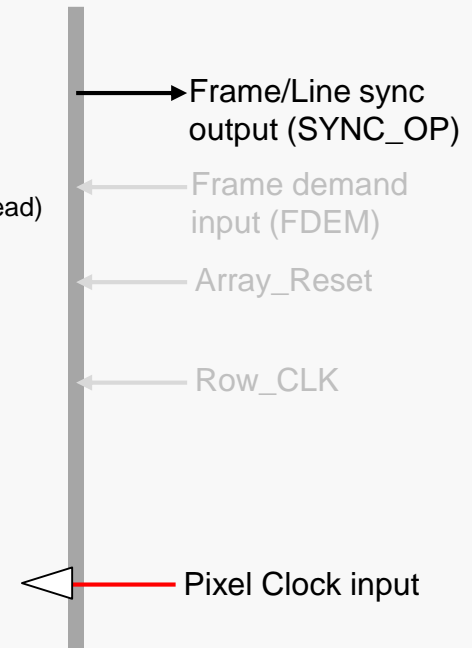
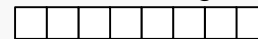
Detector Ctrl. Reg.



Read Mode:

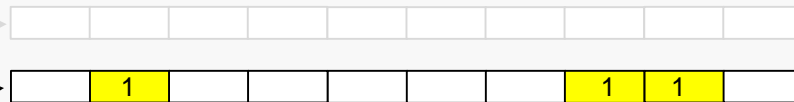
0000=Global Reset-Read(-Read)
0001=Read-Reset-Read

MUX Ctrl. Reg.



Window data register [256:265]

Window reset register [256:265]

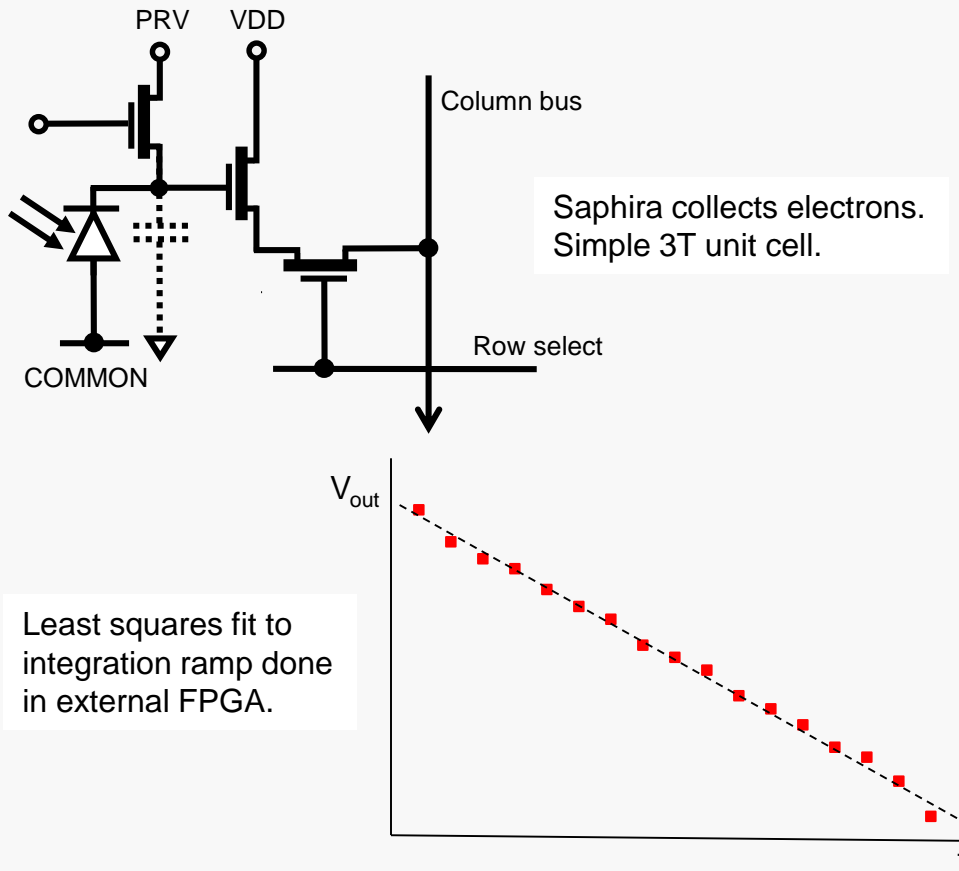


Pixel Stream

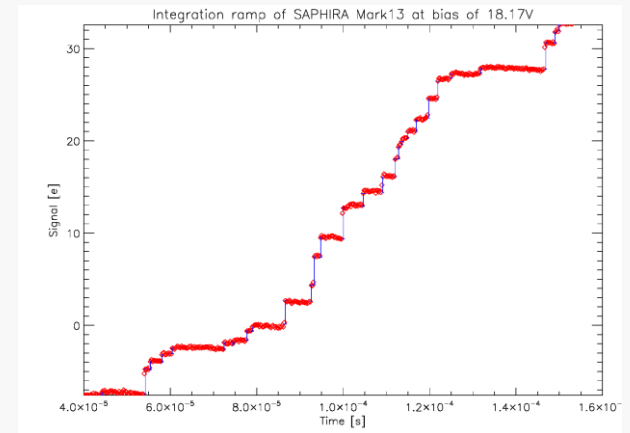


Global Reset-Read(-Read-Read...)

The sequence of FDEM followed by 9 clock transitions can be repeated as many times as necessary for implementation of “sample down the ramp”.

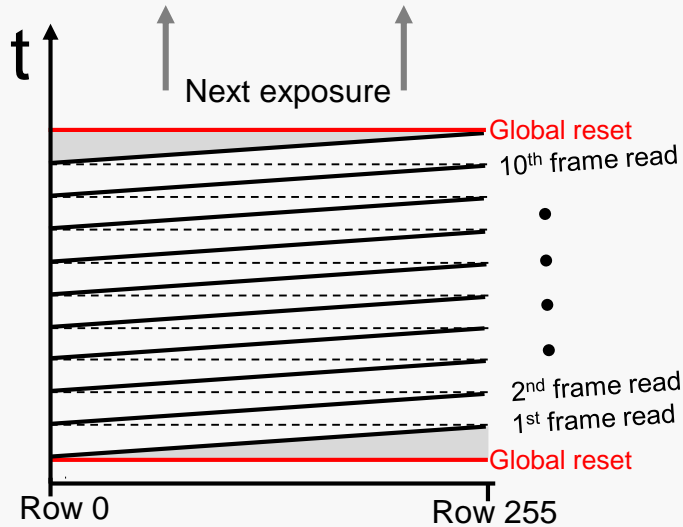


More interestingly, with the internal gain set high, the integration ramp becomes an integration “staircase”. Individual photon events become visible.

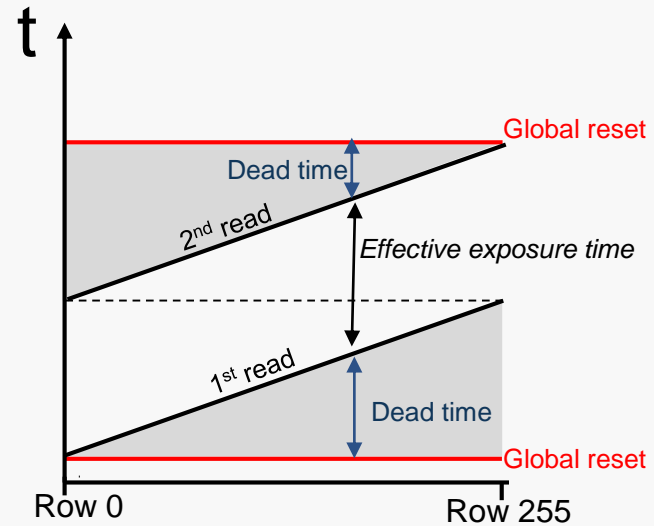


Global Reset-Read(-Read) Speed Limitation

If exposure time \gg read time then only a small amount of signal goes undetected.



If we push the frame rate to the maximum then we just use a single pair of reads during each exposure. In this case 50% of the signal is undetected.

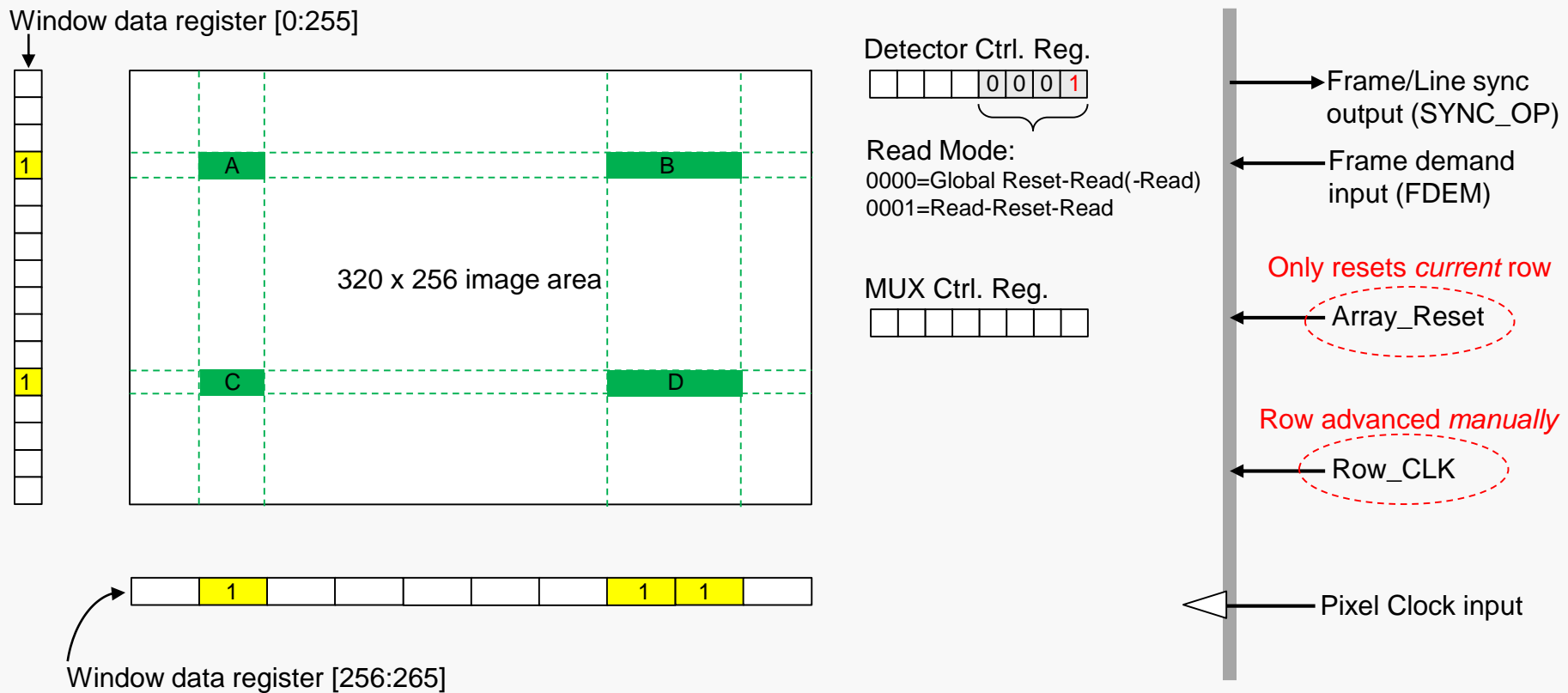


■ Signal collected in these regions is not detected.

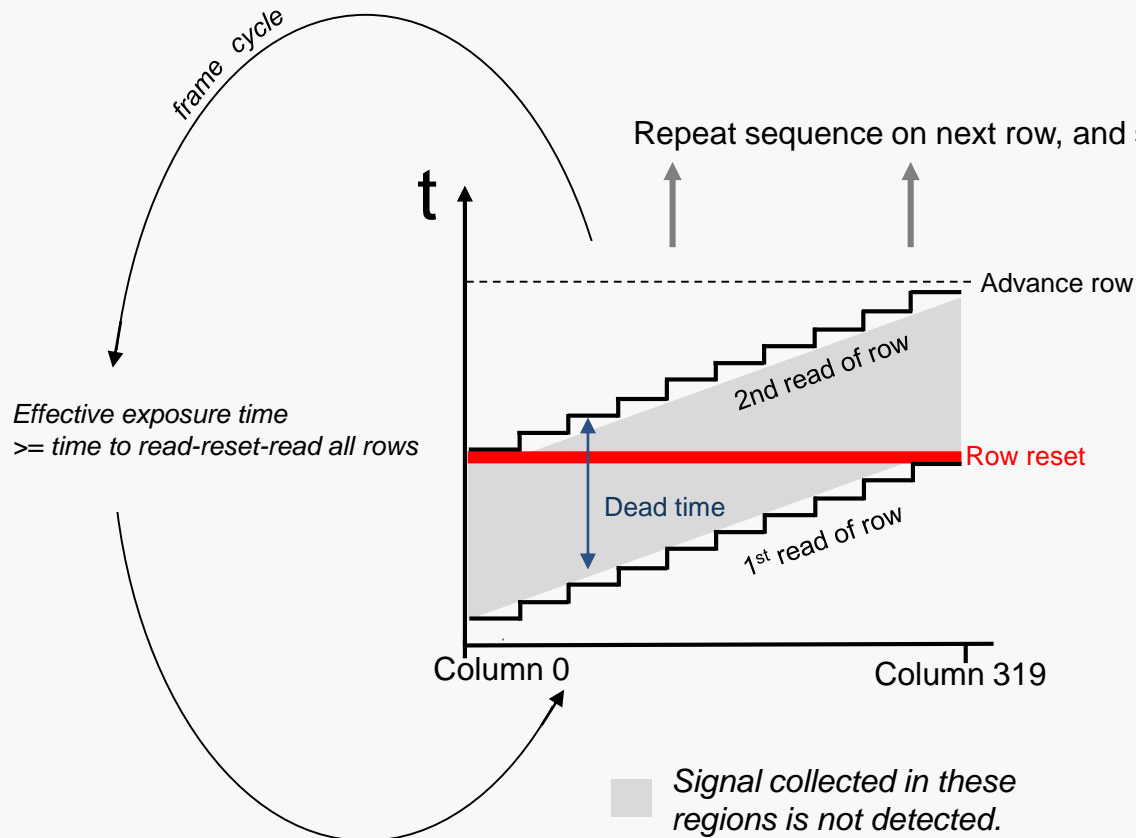


Read-Reset-Read Mode

In this alternative mode, the row advance is under user control and the reset is only applied to the current row. Multiple reads of current row now possible. Maximum frame rate can be achieved with no loss of efficiency.



Read-Reset-Read Mode

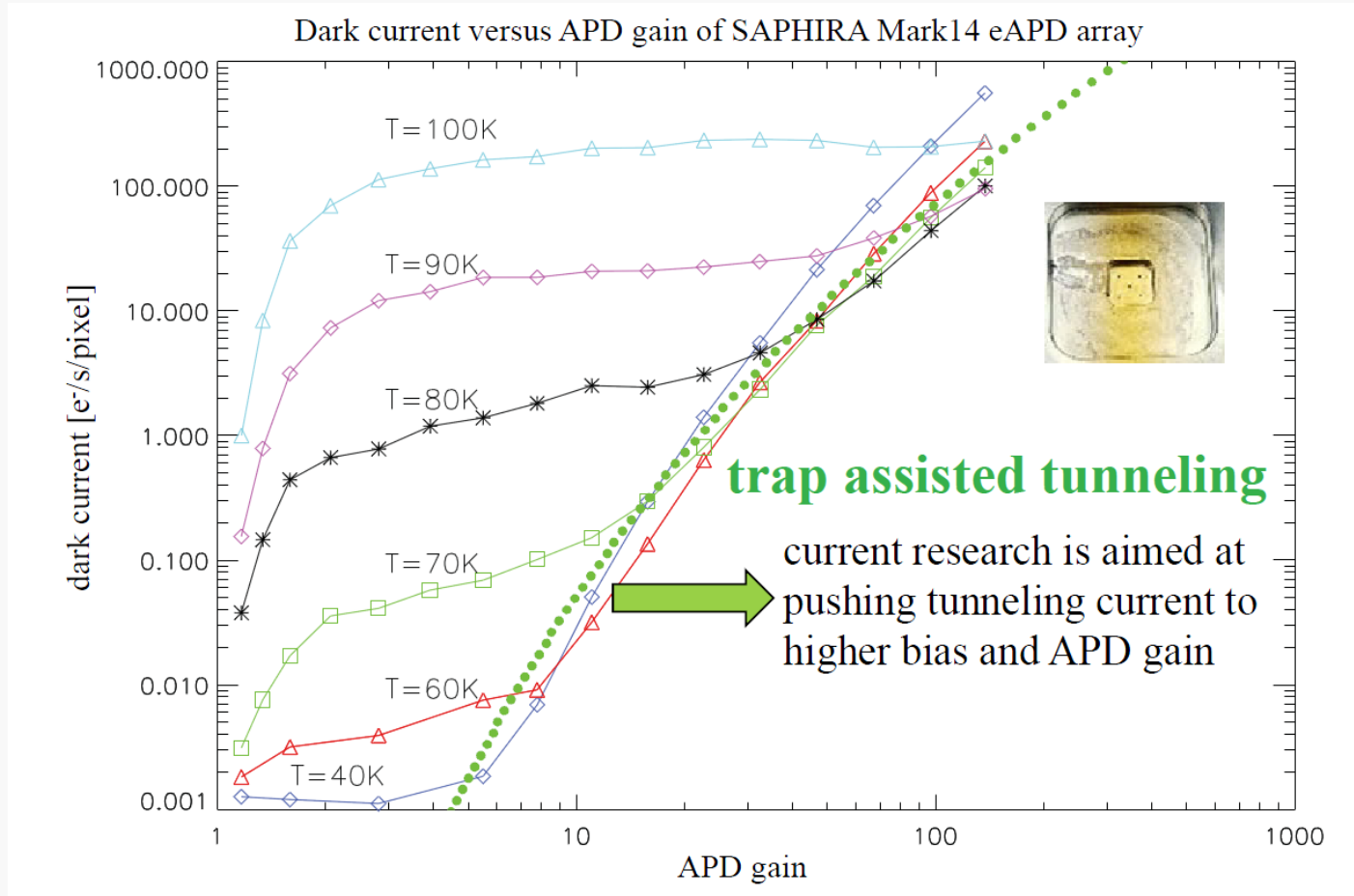


This gives maximum observing efficiency at high frame rates. The “dead time” fraction is now at most =

$$1/(\text{number of rows in the image})$$

Dark Current

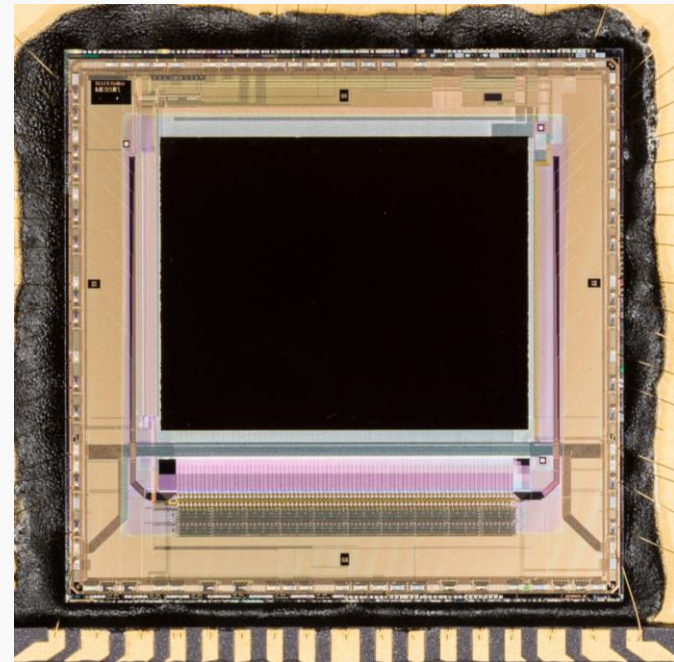
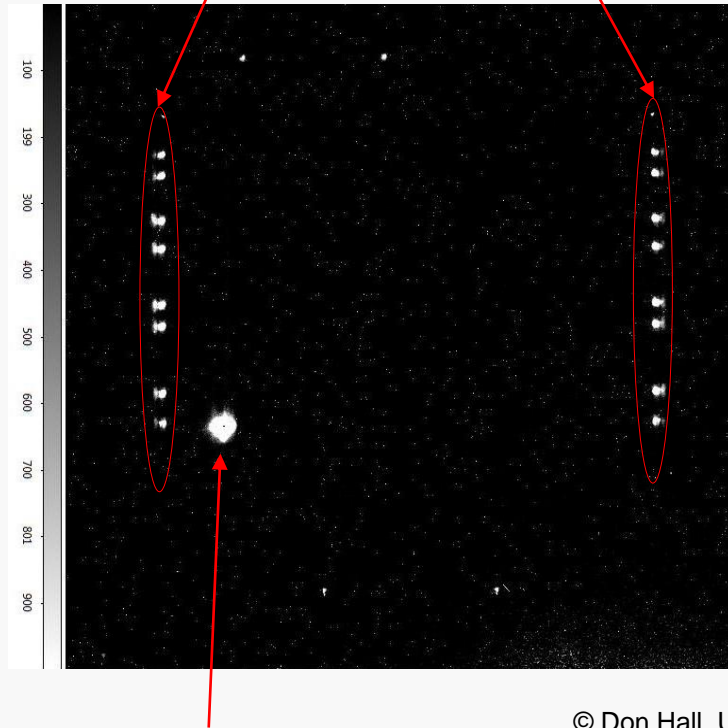
This is the major barrier for the scientific use of eAPD technology



Gert Finger, ESO

Additional metal shielding will be added on future devices.

Inadequately shielded video buffers



© Don Hall, University of Hawaii

Unconnected transistor mask error

Future Science device

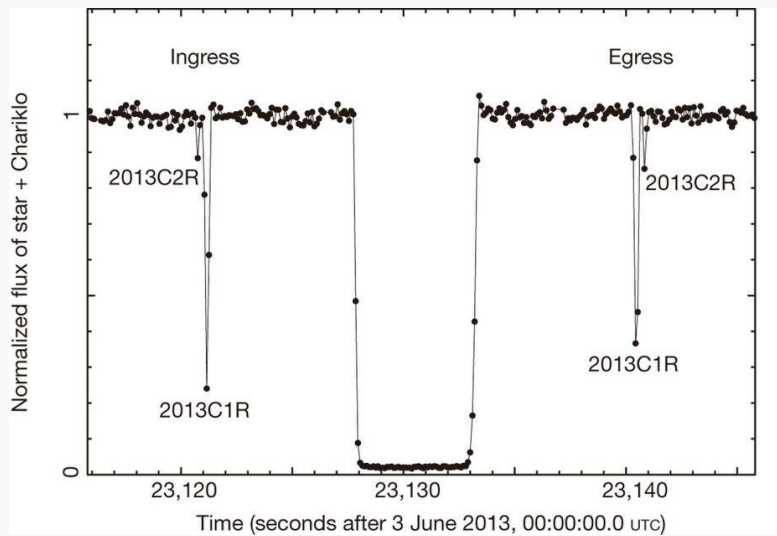
- Very much dependent on reducing glow and dark current
- NASA funded 3-year program between Leonardo, Selex Galileo and U.of Hawaii
- 1k x 1k x 15um device for low-background space-based astronomy
- 3.3V logic compatible, 3-side buttable
- Reference pixels for common mode noise rejection.

Ground based applications also, in regimes where we are detector noise limited:

High resolution spectroscopy

High Time Resolution Astrophysics

Fast occultations



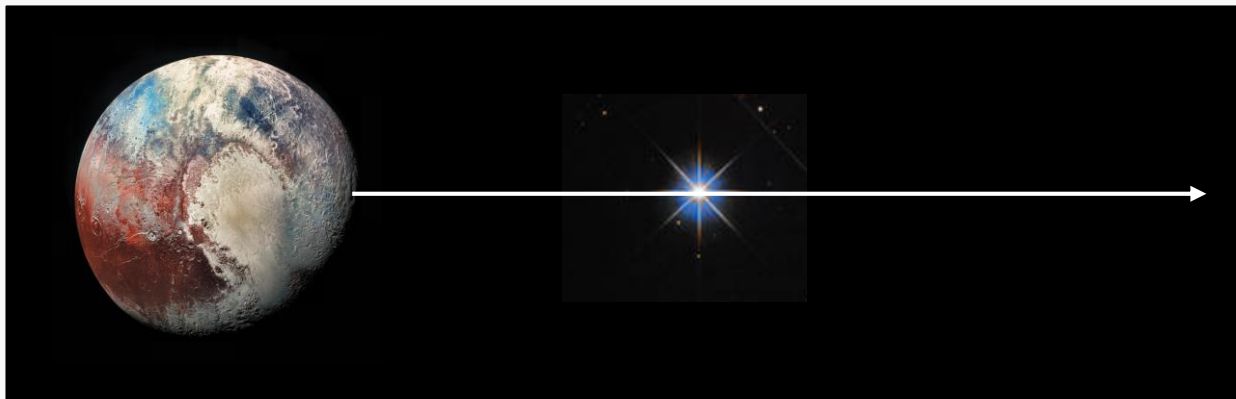
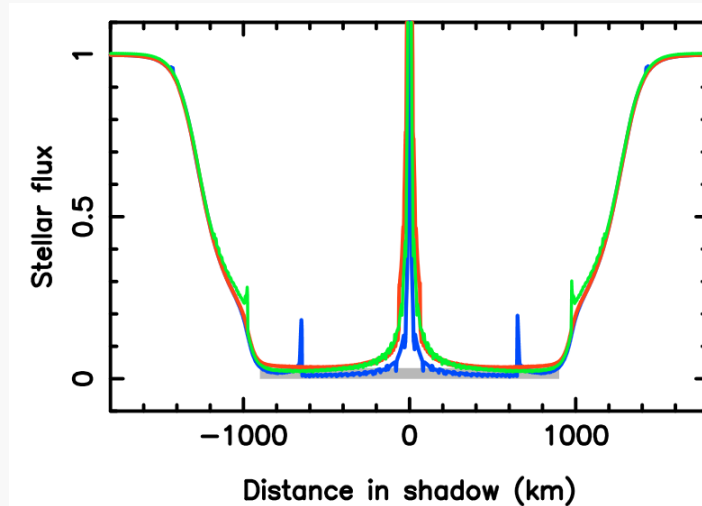
F. Braga-Ribas, Brazil National Observatory



Artists impression of Chariklo asteroid

Science cases: rapid photon starved events

Fast occultations: detection of planetary atmospheres



Transit of Pluto

Science cases: rapid photon starved events

Compact binaries : millisecond flickering

Jets from accreting black holes



Mass transfer onto white dwarf

